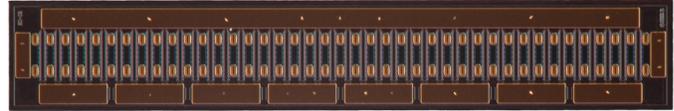


# CG2H80120D

120 W, 8.0 GHz, GaN HEMT Die

## Description

Wolfspeed's CG2H80120D is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT). GaN has superior properties compared to silicon or gallium arsenide, including higher breakdown voltage, higher saturated electron drift velocity, and higher thermal conductivity. GaN HEMTs offer greater power density and wider bandwidths compared to Si and GaAs transistors



PNs: CG2H80120D

## Features

- 15 dB Typical Small Signal Gain at 4 GHz
- 12 dB Typical Small Signal Gain at 8 GHz
- 120 W Typical  $P_{SAT}$
- 28 V Operation
- High Breakdown Voltage
- High Temperature Operation
- Up to 8 GHz Operation
- High Efficiency

## Applications

- 2-Way Private Radio
- Broadband Amplifiers
- Cellular Infrastructure
- Test Instrumentation
- Class A, AB, Linear amplifiers suitable for OFDM, W-CDMA, EDGE, CDMA waveforms

## Packaging Information



- Bare die are shipped in Gel-Pak® containers
- Non-adhesive tacky membrane immobilizes die during shipment

 Large Signal Models Available for ADS and MWO





## Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	$V_{DSS}$	120	V	25°C
Gate-to-Source Voltage	$V_{GS}$	-10, +2		
Storage Temperature	$T_{STG}$	-65, +150	°C	
Operating Junction Temperature	$T_J$	225		
Maximum Forward Gate Current	$I_{GMAX}$	30	mA	25°C
Maximum Drain Current <sup>1</sup>	$I_{DMAX}$	12	A	
Thermal Resistance, Junction to Case (packaged) <sup>2</sup>	$R_{\theta JC}$	1.39	°C/W	85°C
Thermal Resistance, Junction to Case (die only)		0.8		
Mounting Temperature (30 seconds)	$T_s$	320	°C	30 seconds

Notes:

<sup>1</sup> Current limit for long term, reliable operation

<sup>2</sup> Eutectic die attach using 80/20 AuSn mounted to a 60 mil thick CuMoCu carrier

## Electrical Characteristics (Frequency = 4 GHz unless otherwise stated; $T_c = 25^\circ\text{C}$ )

Characteristics	Symbol	Min.	Typ.	Max.	Units	Conditions
<b>DC Characteristics</b>						
Gate Threshold Voltage	$V_{GS(th)}$	-3.8	-3.0	-2.3	$V_{DC}$	$V_{DS} = 10\text{ V}, I_D = 28.8\text{ mA}$
Gate Quiescent Voltage	$V_{GS(Q)}$	—	-2.7	—		$V_{DD} = 28\text{ V}, I_{DQ} = 1000\text{ mA}$
Drain Current	$I_{DSS}$	23.2	28.0	—	A	$V_{DS} = 6.0\text{ V}, V_{GS} = 2.0\text{ V}$
Drain-Source Breakdown Voltage	$V_{BD}$	84	—	—	V	$V_{GS} = -8\text{ V}, I_D = 28.8\text{ mA}$
On Resistance	$R_{ON}$	—	0.08	—	$\Omega$	$V_{DS} = 0.10\text{ V}$
Gate Forward Voltage	$V_{G-ON}$	—	1.9	—	V	$I_{GS} = 28.8\text{ mA}$
<b>RF Characteristics</b>						
Small Signal Gain	$G_{SS}$	—	15	—	dB	$V_{DD} = 28\text{ V}, I_{DQ} = 1000\text{ mA}$
Saturated Output Power <sup>1</sup>	$P_{SAT}$	—	120	—	W	
Drain Efficiency <sup>2</sup>	$\eta$	—	65	—	%	$V_{DD} = 28\text{ V}, I_{DQ} = 1000\text{ mA}, P_{SAT} = 120\text{ W}$
Intermodulation Distortion	IM3	—	-30	—	dBc	$V_{DD} = 28\text{ V}, I_{DQ} = 1000\text{ mA}, P_{OUT} = 120\text{ W PEP}$
Output Mismatch Stress <sup>3</sup>	VSWR	—	—	10 : 1	$\Psi$	$V_{DD} = 28\text{ V}, I_{DQ} = 1000\text{ mA}, P_{OUT} = 120\text{ W (CW)}$
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{GS}$	—	31.2	—	pF	$V_{DS} = 28\text{ V}, V_{GS} = -8\text{ V}, f = 1\text{ MHz}$
Output Capacitance	$C_{DS}$	—	10.6	—		
Feedback Capacitance	$C_{GD}$	—	1.5	—		

Notes:

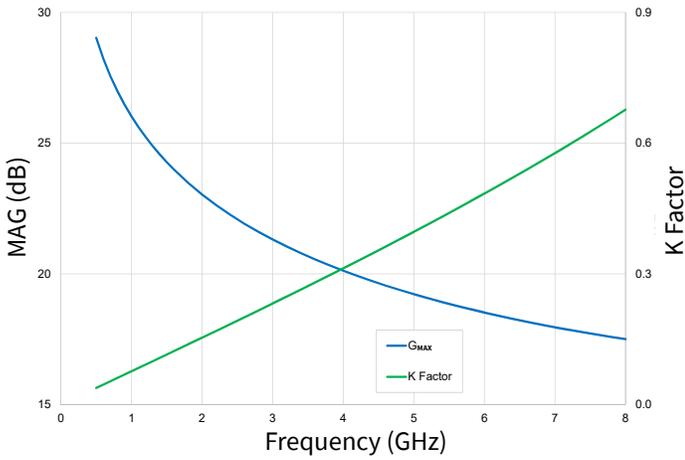
<sup>1</sup>  $P_{SAT}$  is defined as  $I_G = 2.8\text{ mA}$

<sup>2</sup> Drain Efficiency =  $P_{OUT} / P_{DC}$

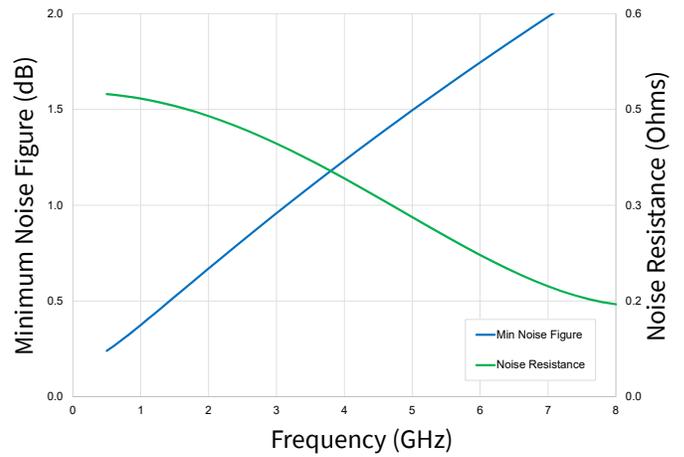
<sup>3</sup> No damage at all phase angles



### Typical Performance



**Figure 1.** Simulated Maximum Available Gain and K Factor  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 1000\text{ mA}$



**Figure 2.** Simulated Minimum Noise Figure and Noise Resistance vs. Frequency  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 1000\text{ mA}$

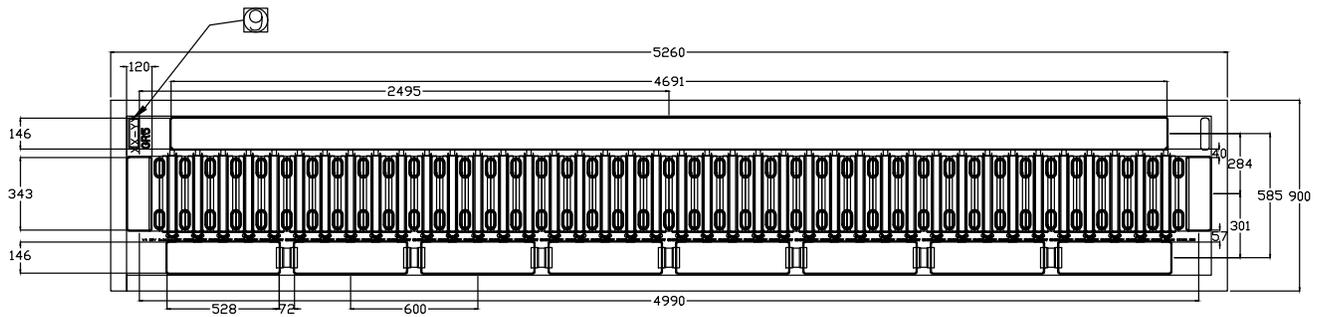
Intrinsic die parameters - reference planes at centers of gate and drain bonding pads. No wire bonds assumed.

### Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Classification Level	Test Methodology
Human Body Model	HBM	TBD	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D



## Die Dimensions (units in microns)



## Assembly Notes:

- Recommended solder is AuSn (80/20) solder. Refer to Wolfspeed's website for the Eutectic Die Bond Procedure application note at <https://www.wolfspeed.com/rf/document-library>
- Vacuum collet is the preferred method of pick-up.
- The backside of the die is the Source (ground) contact.
- Die back side gold plating is 5 microns thick minimum.
- Thermosonic ball or wedge bonding are the preferred connection methods.
- Gold wire must be used for connections.
- Use the die label (XX-YY) for correct orientation.



**Typical Package S-Parameters for CG2H80120D**  
 (Small Signal,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 500\text{ mA}$ , magnitude/angle)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
0.5	0.958	-174.57	5.11	84.00	0.009	-5.31	0.829	-176.75
0.6	0.958	-175.39	4.24	81.90	0.009	-7.28	0.831	-176.74
0.7	0.958	-175.96	3.62	79.93	0.009	-9.11	0.833	-176.65
0.8	0.959	-176.38	3.15	78.05	0.009	-10.85	0.835	-176.53
0.9	0.959	-176.71	2.78	76.24	0.009	-12.52	0.837	-176.39
1.0	0.960	-176.96	2.49	74.49	0.009	-14.14	0.839	-176.23
1.1	0.960	-177.16	2.25	72.79	0.009	-15.70	0.842	-176.08
1.2	0.961	-177.32	2.04	71.12	0.009	-17.23	0.845	-175.92
1.3	0.962	-177.46	1.87	69.50	0.008	-18.72	0.848	-175.77
1.4	0.962	-177.58	1.72	67.91	0.008	-20.17	0.851	-175.63
1.5	0.963	-177.68	1.59	66.36	0.008	-21.58	0.854	-175.49
1.6	0.964	-177.76	1.48	64.84	0.008	-22.96	0.857	-175.37
1.8	0.965	-177.91	1.29	61.91	0.008	-25.61	0.863	-175.15
2.0	0.966	-178.03	1.13	59.11	0.008	-28.14	0.870	-174.98
2.2	0.968	-178.14	1.00	56.45	0.008	-30.53	0.876	-174.85
2.4	0.969	-178.23	0.90	53.90	0.007	-32.80	0.883	-174.75
2.6	0.971	-178.32	0.81	51.48	0.007	-34.94	0.889	-174.69
2.8	0.972	-178.40	0.73	49.18	0.007	-36.97	0.895	-174.67
3.0	0.973	-178.48	0.67	46.99	0.007	-38.88	0.901	-174.66
3.2	0.975	-178.56	0.61	44.90	0.007	-40.69	0.906	-174.69
3.4	0.976	-178.64	0.56	42.92	0.007	-42.39	0.911	-174.73
3.6	0.977	-178.72	0.51	41.04	0.006	-44.00	0.916	-174.78
3.8	0.978	-178.79	0.47	39.25	0.006	-45.51	0.921	-174.85
4.0	0.979	-178.86	0.44	37.54	0.006	-46.94	0.925	-174.94
4.2	0.980	-178.94	0.41	35.92	0.006	-48.29	0.929	-175.02
4.4	0.981	-179.01	0.38	34.37	0.006	-49.56	0.933	-175.12
4.6	0.982	-179.08	0.35	32.89	0.005	-50.76	0.936	-175.22
4.8	0.982	-179.15	0.33	31.48	0.005	-51.89	0.940	-175.32
5.0	0.983	-179.22	0.31	30.13	0.005	-52.95	0.943	-175.43
5.2	0.984	-179.29	0.29	28.84	0.005	-53.96	0.946	-175.54
5.4	0.984	-179.36	0.27	27.61	0.005	-54.92	0.948	-175.65
5.6	0.985	-179.43	0.26	26.43	0.005	-55.82	0.951	-175.76
5.8	0.985	-179.50	0.24	25.29	0.005	-56.67	0.953	-175.87
6.0	0.986	-179.56	0.23	24.20	0.005	-57.48	0.955	-175.97
6.2	0.986	-179.63	0.22	23.15	0.004	-58.24	0.957	-176.08
6.4	0.987	-179.69	0.21	22.14	0.004	-58.97	0.959	-176.19
6.6	0.987	-179.76	0.19	21.17	0.004	-59.65	0.961	-176.29
6.8	0.988	-179.82	0.19	20.24	0.004	-60.30	0.963	-176.4
7.0	0.988	-179.88	0.18	19.33	0.004	-60.92	0.964	-176.50
7.2	0.988	-179.94	0.17	18.46	0.004	-61.50	0.966	-176.60
7.4	0.989	-179.99	0.16	17.62	0.004	-62.06	0.967	-176.70
7.6	0.989	-179.93	0.15	16.80	0.004	-62.59	0.968	-176.79
7.8	0.989	-179.87	0.15	16.01	0.004	-63.09	0.969	-176.89
8.0	0.990	-179.82	0.14	15.24	0.004	-63.56	0.971	-176.98

To download the s-parameters in s2p format, go to the [CG2H80120D](#) Product page and click on the documentation tab.



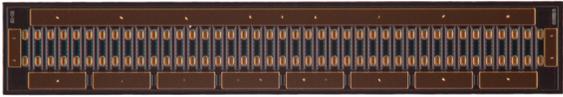
**Typical Package S-Parameters for CG2H80120D**  
 (Small Signal,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 1000\text{ mA}$ , magnitude/angle)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
0.5	0.969	-175.19	5.14	85.64	0.006	-3.62	0.864	-177.97
0.6	0.969	-175.95	4.28	83.93	0.006	-5.18	0.865	-177.99
0.7	0.969	-176.50	3.66	82.33	0.006	-6.63	0.866	-177.96
0.8	0.969	-176.90	3.19	80.82	0.006	-8.00	0.867	-177.90
0.9	0.969	-177.22	2.83	79.35	0.006	-9.31	0.868	-177.82
1.0	0.970	-177.46	2.53	77.93	0.006	-10.59	0.869	-177.73
1.1	0.970	-177.67	2.29	76.55	0.006	-11.83	0.871	-177.63
1.2	0.970	-177.83	2.09	75.19	0.006	-13.04	0.872	-177.53
1.3	0.970	-177.97	1.92	73.86	0.006	-14.22	0.873	-177.43
1.4	0.971	-178.09	1.77	72.55	0.006	-15.38	0.875	-177.33
1.5	0.971	-178.19	1.65	71.26	0.006	-16.52	0.877	-177.23
1.6	0.971	-178.28	1.53	69.99	0.006	-17.64	0.878	-177.13
1.8	0.972	-178.43	1.35	67.52	0.006	-19.81	0.882	-176.95
2.0	0.973	-178.55	1.19	65.13	0.006	-21.91	0.885	-176.79
2.2	0.973	-178.66	1.07	62.81	0.006	-23.93	0.889	-176.64
2.4	0.974	-178.74	0.96	60.57	0.006	-25.87	0.893	-176.52
2.6	0.975	-178.82	0.87	58.40	0.006	-27.74	0.897	-176.42
2.8	0.976	-178.90	0.80	56.31	0.006	-29.53	0.901	-176.33
3.0	0.977	-178.96	0.73	54.29	0.005	-31.25	0.904	-176.27
3.2	0.977	-179.03	0.67	52.34	0.005	-32.90	0.908	-176.22
3.4	0.978	-179.09	0.62	50.46	0.005	-34.48	0.912	-176.19
3.6	0.979	-179.15	0.58	48.65	0.005	-35.99	0.915	-176.17
3.8	0.979	-179.21	0.54	46.91	0.005	-37.43	0.919	-176.17
4.0	0.980	-179.27	0.50	45.23	0.005	-38.80	0.922	-176.17
4.2	0.981	-179.33	0.47	43.61	0.005	-40.11	0.925	-176.19
4.4	0.981	-179.38	0.44	42.06	0.005	-41.37	0.929	-176.22
4.6	0.982	-179.44	0.41	40.56	0.005	-42.56	0.931	-176.25
4.8	0.983	-179.50	0.38	39.11	0.004	-43.70	0.934	-176.29
5.0	0.983	-179.55	0.36	37.72	0.004	-44.79	0.937	-176.34
5.2	0.984	-179.61	0.34	36.37	0.004	-45.82	0.940	-176.39
5.4	0.984	-179.67	0.32	35.08	0.004	-46.81	0.942	-176.44
5.6	0.985	-179.72	0.30	33.83	0.004	-47.75	0.944	-176.50
5.8	0.985	-179.78	0.29	32.62	0.004	-48.64	0.947	-176.57
6.0	0.986	-179.83	0.27	31.45	0.004	-49.49	0.949	-176.63
6.2	0.986	-179.89	0.26	30.33	0.004	-50.30	0.951	-176.70
6.4	0.986	-179.94	0.25	29.24	0.004	-51.08	0.952	-176.76
6.6	0.987	-180.00	0.24	28.19	0.004	-51.81	0.954	-176.83
6.8	0.987	179.95	0.23	27.17	0.004	-52.51	0.956	-176.90
7.0	0.987	179.9	0.22	26.18	0.003	-53.18	0.958	-176.97
7.2	0.988	179.84	0.21	25.22	0.003	-53.81	0.959	-177.05
7.4	0.988	179.79	0.20	24.29	0.003	-54.42	0.961	-177.12
7.6	0.988	179.73	0.19	23.39	0.003	-54.99	0.962	-177.19
7.8	0.989	179.68	0.18	22.52	0.003	-55.54	0.963	-177.26
8.0	0.989	179.63	0.17	21.67	0.003	-56.05	0.964	-177.33

To download the s-parameters in s2p format, go to the [CG2H80120D](#) Product page and click on the documentation tab.



### Product Ordering Information

Order Number	Description	Unit of Measure	Image
CG2H80120D	GaN HEMT Bare Die	Each	 A microscopic image of a GaN HEMT bare die, showing a rectangular chip with a grid of small, gold-colored pads or contacts along its edges.

**For more information, please contact:**

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## Notes & Disclaimer

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